Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.013 inches
Overall Height:
Between 0.005 inches and 0.008 inches
Overall Width:
0.013 inches
Mounting Method:
Compression
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, instantaneous
Current Rating Per Characteristic:
10.00 microamperes forward current, average outside diameter
Maximum Operating Tempurature Per Measurement Point:
85.0 degrees celsius junction
Precious Material:
Gold
Terminal Type And Quantity:
2 bonding pad
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0